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Applications of "[Embedded - Microcontrollers](#)"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M0
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I ² C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, I ² S, POR, PWM, WDT
Number of I/O	18
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 8x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	24-VFQFN Exposed Pad
Supplier Device Package	PG-VQFN-24-19
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/xmc1100q024f0064abxuma1

XMC1100

Microcontroller Series
for Industrial Applications

XMC1000 Family

ARM[®] Cortex[™]-M0
32-bit processor core

Data Sheet

V1.4 2014-05

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Summary of Features

- High code density with 32-bit performance
- Single cycle 32-bit hardware multiplier
- System timer (SysTick) for Operating System support
- Ultra low power consumption
- Nested Vectored Interrupt Controller (NVIC)
- Event Request Unit (ERU) for programmable processing of external and internal service requests

On-Chip Memories

- 8 kbytes on-chip ROM
- 16 kbytes on-chip high-speed SRAM
- up to 64 kbytes on-chip Flash program and data memory

On-Chip Peripherals

- Two Universal Serial Interface Channels (USIC), usable as UART, double-SPI, quad-SPI, IIC, IIS and LIN interfaces
- A/D Converters, up to 12 channels, includes a 12-bit analog to digital converter
- Capture/Compare Units 4 (CCU4) for use as general purpose timers
- Window Watchdog Timer (WDT) for safety sensitive applications
- Real Time Clock module with alarm support (RTC)
- System Control Unit (SCU) for system configuration and control
- Pseudo random number generator (PRNG), provides random data with fast generation times
- Temperature Sensor (TSE)

Input/Output Lines

- Programmable port driver control module (PORTS)
- Individual bit addressability
- Tri-stated in input mode
- Push/pull or open drain output mode
- Configurable pad hysteresis

On-Chip Debug Support

- Support for debug features: 4 breakpoints, 2 watchpoints
- Various interfaces: ARM serial wire debug (SWD), single pin debug (SPD)

1.1 Ordering Information

The ordering code for an Infineon microcontroller provides an exact reference to a specific product. The code "XMC1<DDD>-<Z><PPP><T><FFFF>" identifies:

- <DDD> the derivatives function set

Summary of Features

- <Z> the package variant
 - T: TSSOP
 - Q: VQFN
- <PPP> package pin count
- <T> the temperature range:
 - F: -40°C to 85°C
 - X: -40°C to 105°C
- <FFFF> the Flash memory size.

For ordering codes for the XMC1100 please contact your sales representative or local distributor.

This document describes several derivatives of the XMC1100 series, some descriptions may not apply to a specific product. Please see [Table 1](#).

For simplicity the term **XMC1100** is used for all derivatives throughout this document.

1.2 Device Types

These device types are available and can be ordered through Infineon's direct and/or distribution channels.

Table 1 Synopsis of XMC1100 Device Types

Derivative	Package	Flash Kbytes	SRAM Kbytes
XMC1100-T016F0008	PG-TSSOP-16-8	8	16
XMC1100-T016F0016	PG-TSSOP-16-8	16	16
XMC1100-T016F0032	PG-TSSOP-16-8	32	16
XMC1100-T016F0064	PG-TSSOP-16-8	64	16
XMC1100-T016X0064	PG-TSSOP-16-8	64	16
XMC1100-T038F0016	PG-TSSOP-38-9	16	16
XMC1100-T038F0032	PG-TSSOP-38-9	32	16
XMC1100-T038F0064	PG-TSSOP-38-9	64	16
XMC1100-T038X0064	PG-TSSOP-38-9	64	16
XMC1100-Q024F0008	PG-VQFN-24-19	8	16
XMC1100-Q024F0016	PG-VQFN-24-19	16	16
XMC1100-Q024F0032	PG-VQFN-24-19	32	16
XMC1100-Q024F0064	PG-VQFN-24-19	64	16
XMC1100-Q040F0016	PG-VQFN-40-13	16	16

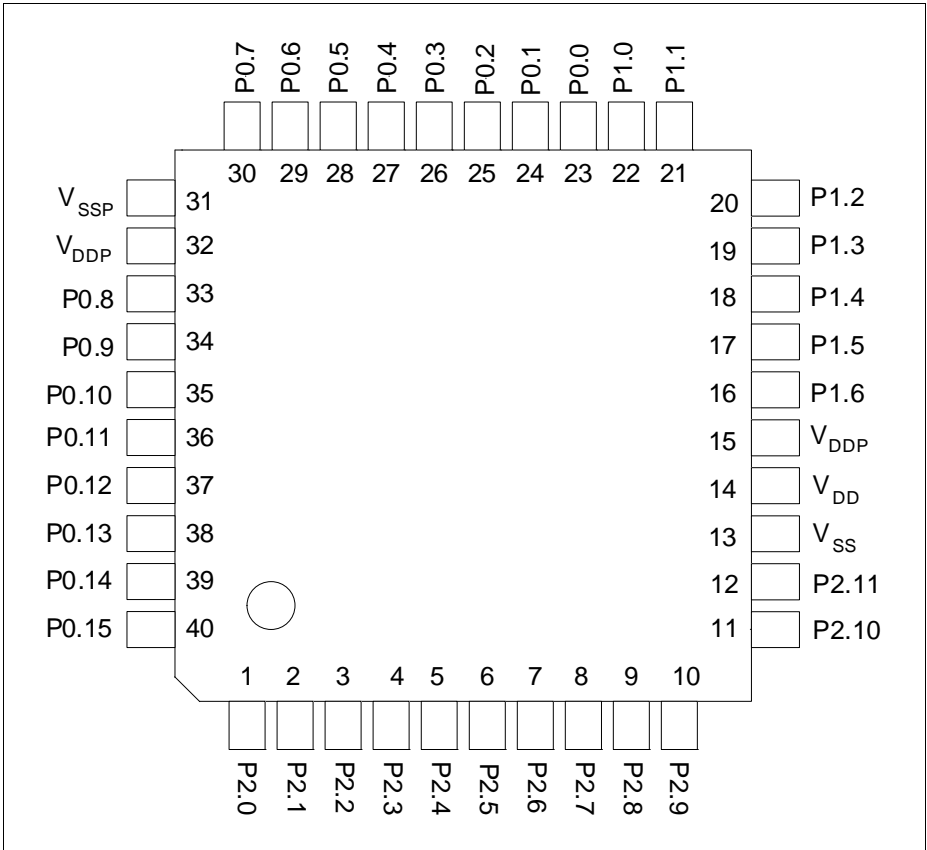


Figure 7 XMC1100 PG-VQFN-40 Pin Configuration (top view)

Table 8 Port I/O Functions

Function	Outputs								Inputs									
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	HWO0	HWO1	HWI0	HWI1	Input	Input	Input	Input	Input	Input	
P0.0	ERU0. PDOU0		ERU0. GOUT0	CCU40.OUT0		USIC0_CH0. SELO0	USIC0_CH1. SELO0					CCU40.IN0C				USIC0_CH0. DX2A	USIC0_CH1. DX2A	
P0.1	ERU0. PDOU1		ERU0. GOUT1	CCU40.OUT1			SCU_VDROP					CCU40.IN1C						
P0.2	ERU0. PDOU2		ERU0. GOUT2	CCU40.OUT2		VADC0. EMUX02						CCU40.IN2C						
P0.3	ERU0. PDOU3		ERU0. GOUT3	CCU40.OUT3		VADC0. EMUX01						CCU40.IN3C						
P0.4				CCU40.OUT1		VADC0. EMUX00	WWDT. SERVICE_OU T											
P0.5				CCU40.OUT0														
P0.6				CCU40.OUT0		USIC0_CH1. MCLKOUT	USIC0_CH1. DOUT0					CCU40.IN0B				USIC0_CH1. DX0C		
P0.7				CCU40.OUT1		USIC0_CH0. SCLKOUT	USIC0_CH1. DOUT0					CCU40.IN1B				USIC0_CH0. DX1C	USIC0_CH1. DX0D	USIC0_CH1. DX1C
P0.8				CCU40.OUT2		USIC0_CH0. SCLKOUT	USIC0_CH1. SCLKOUT					CCU40.IN2B				USIC0_CH0. DX1B	USIC0_CH1. DX1B	
P0.9				CCU40.OUT3		USIC0_CH0. SELO0	USIC0_CH1. SELO0					CCU40.IN3B				USIC0_CH0. DX2B	USIC0_CH1. DX2B	
P0.10						USIC0_CH0. SELO1	USIC0_CH1. SELO1									USIC0_CH0. DX2C	USIC0_CH1. DX2C	
P0.11				USIC0_CH0. MCLKOUT		USIC0_CH0. SELO2	USIC0_CH1. SELO2									USIC0_CH0. DX2D	USIC0_CH1. DX2D	
P0.12						USIC0_CH0. SELO3						CCU40.IN0A	CCU40.IN1A	CCU40.IN2A	CCU40.IN3A	USIC0_CH0. DX2E		
P0.13	WWDT. SERVICE_OU T					USIC0_CH0. SELO4										USIC0_CH0. DX2F		
P0.14						USIC0_CH0. DOUT0	USIC0_CH0. SCLKOUT									USIC0_CH0. DX0A	USIC0_CH0. DX1A	
P0.15						USIC0_CH0. DOUT0	USIC0_CH1. MCLKOUT									USIC0_CH0. DX0B		
P1.0		CCU40.OUT0					USIC0_CH0. DOUT0	USIC0_CH0. DOUT0			USIC0_CH0. HWIN0					USIC0_CH0. DX0C		
P1.1	VADC0. EMUX00	CCU40.OUT1				USIC0_CH0. DOUT0	USIC0_CH1. SELO0	USIC0_CH0. DOUT1			USIC0_CH0. HWIN1					USIC0_CH0. DX0D	USIC0_CH0. DX1D	USIC0_CH1. DX2E
P1.2	VADC0. EMUX01	CCU40.OUT2					USIC0_CH1. DOUT0	USIC0_CH0. DOUT2			USIC0_CH0. HWIN2					USIC0_CH1. DX0B		
P1.3	VADC0. EMUX02	CCU40.OUT3				USIC0_CH1. SCLKOUT	USIC0_CH1. DOUT0	USIC0_CH0. DOUT3			USIC0_CH0. HWIN3					USIC0_CH1. DX0A	USIC0_CH1. DX1A	
P1.4	VADC0. EMUX10	USIC0_CH1. SCLKOUT				USIC0_CH0. SELO0	USIC0_CH1. SELO1									USIC0_CH0. DX5E	USIC0_CH1. DX5E	
P1.5	VADC0. EMUX11					USIC0_CH0. SELO1	USIC0_CH1. SELO2									USIC0_CH1. DX5F		

Table 8 Port I/O Functions (cont'd)

Function	Outputs									Inputs								
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	HWO0	HWO1	HWI0	HWI1	Input	Input	Input	Input	Input	Input	Input
P1.6	VADC0. EMUX12	USIC0_CH1.D OUT0		USIC0_CH0.S CLKOUT		USIC0_CH0.S ELOS	USIC0_CH1.S ELOS							USIC0_CH0.D XSF				
P2.0	ERU0. PDOUT3	CCU40.OUT0	ERU0. GOUT3			USIC0_CH0. DOUT0	USIC0_CH0. SCLKOUT						VADC0. G0CH5		ERU0.0B0	USIC0_CH0. DX0E	USIC0_CH0. DX1E	USIC0_CH1. DX2F
P2.1	ERU0. PDOUT2	CCU40.OUT1	ERU0. GOUT2			USIC0_CH0. DOUT0	USIC0_CH1. SCLKOUT						VADC0. G0CH6		ERU0.1B0	USIC0_CH0. DX0F	USIC0_CH1. DX3A	USIC0_CH1. DX4A
P2.2													VADC0. G0CH7		ERU0.0B1	USIC0_CH0. DX3A	USIC0_CH0. DX4A	USIC0_CH1. DX5A
P2.3													VADC0. G1CH5		ERU0.1B1	USIC0_CH0. DX5B	USIC0_CH1. DX3C	USIC0_CH1. DX4C
P2.4													VADC0. G1CH6		ERU0.0A1	USIC0_CH0. DX3B	USIC0_CH0. DX4B	USIC0_CH1. DX5B
P2.5													VADC0. G1CH7		ERU0.1A1	USIC0_CH0. DX5D	USIC0_CH1. DX3E	USIC0_CH1. DX4E
P2.6													VADC0. G0CH0		ERU0.2A1	USIC0_CH0. DX3E	USIC0_CH0. DX4E	USIC0_CH1. DX5D
P2.7													VADC0. G1CH1		ERU0.3A1	USIC0_CH0. DX5C	USIC0_CH1. DX3D	USIC0_CH1. DX4D
P2.8													VADC0. G0CH1	VADC0. G1CH0	ERU0.3B1	USIC0_CH0. DX3D	USIC0_CH0. DX4D	USIC0_CH1. DX5C
P2.9													VADC0. G0CH2	VADC0. G1CH4	ERU0.3B0	USIC0_CH0. DX5A	USIC0_CH1. DX3B	USIC0_CH1. DX4B
P2.10	ERU0. PDOUT1	CCU40.OUT2	ERU0. GOUT1				USIC0_CH1. DOUT0						VADC0. G0CH3	VADC0. G1CH2	ERU0.2B0	USIC0_CH0. DX3C	USIC0_CH0. DX4C	USIC0_CH1. DX0F
P2.11	ERU0. PDOUT0	CCU40.OUT3	ERU0. GOUT0			USIC0_CH1. SCLKOUT	USIC0_CH1. DOUT0						VADC0. G0CH4	VADC0. G1CH3	ERU0.2B1	USIC0_CH1. DX0E	USIC0_CH1. DX1E	

3 Electrical Parameter

This section provides the electrical parameter which are implementation-specific for the XMC1100.

3.1 General Parameters

3.1.1 Parameter Interpretation

The parameters listed in this section represent partly the characteristics of the XMC1100 and partly its requirements on the system. To aid interpreting the parameters easily when evaluating them for a design, they are indicated by the abbreviations in the "Symbol" column:

- **CC**
Such parameters indicate **C**ontroller **C**haracteristics, which are distinctive feature of the XMC1100 and must be regarded for a system design.
- **SR**
Such parameters indicate **S**ystem **R**equirements, which must be provided by the application system in which the XMC1100 is designed in.

Table 11 Input/Output Characteristics (Operating Conditions apply) (cont'd)

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
Maximum current into V_{DDP} (TSSOP28/16, VQFN24)	I_{MVDD1}	SR	–	130	mA	³⁾
Maximum current into V_{DDP} (TSSOP38, VQFN40)	I_{MVDD2}	SR	–	260	mA	³⁾
Maximum current out of V_{SS} (TSSOP28/16, VQFN24)	I_{MVSS1}	SR	–	130	mA	³⁾
Maximum current out of V_{SS} (TSSOP38, VQFN40)	I_{MVSS2}	SR	–	260	mA	³⁾

- 1) Not subject to production test, verified by design/characterization. Hysteresis is implemented to avoid meta stable states and switching due to internal ground bounce. It cannot be guaranteed that it suppresses switching due to external system noise.
- 2) An additional error current (I_{INL}) will flow if an overload current flows through an adjacent pin.
- 3) Not subject to production test, verified by design/characterization.
- 4) Not subject to production test, verified by design/characterization. However, for applications with strict low power-down current requirements, it is mandatory that no active voltage source is supplied at any GPIO pin when V_{DDP} is powered off.

Table 12 ADC Characteristics (Operating Conditions apply) (cont'd)

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Maximum sample rate in 8-bit mode ³⁾	f_{C8} CC	–	–	$f_{\text{ADC}} / 38.5$	–	1 sample pending
		–	–	$f_{\text{ADC}} / 54.5$	–	2 samples pending
DNL error	EA_{DNL} CC	–	±2.0	–	LSB 12	
INL error	EA_{INL} CC	–	±4.0	–	LSB 12	
Gain error with external reference	EA_{GAIN} CC	–	±0.5	–	%	SHSCFG.AREF = 00 _B (calibrated)
Gain error with internal reference	EA_{GAIN} CC	–	±3.6	–	%	SHSCFG.AREF = 1X _B (calibrated), -40°C - 105°C
		–	±2.0	–	%	SHSCFG.AREF = 1X _B (calibrated), 0°C - 85°C
Offset error	EA_{OFF} CC	–	±6.0	–	LSB 12	Calibrated

- 1) Not subject to production test, verified by design/characterization.
- 2) No pending samples assumed, excluding sampling time and calibration.
- 3) Includes synchronization and calibration (average of gain and offset calibration).

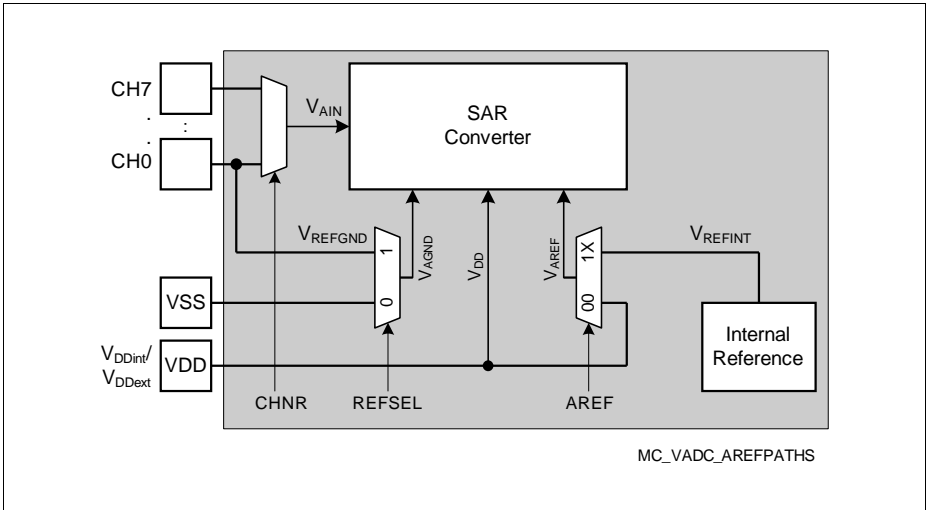


Figure 8 ADC Voltage Supply

3.2.4 Power Supply Current

The total power supply current defined below consists of a leakage and a switching component.

Application relevant values are typically lower than those given in the following tables, and depend on the customer's system operating conditions (e.g. thermal connection or used application configurations).

Table 14 Power Supply Parameters¹⁾

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ. ²⁾	Max.		
Active mode current ³⁾	I_{DDPA} CC	–	8.4	11.0	mA	$f_{MCLK} = 32$ MHz $f_{PCLK} = 64$ MHz
		–	3.7	–	mA	$f_{MCLK} = 1$ MHz $f_{PCLK} = 1$ MHz
Sleep mode current Peripherals clock enabled ⁴⁾	I_{DDPSE} CC	–	5.9	–	mA	$f_{MCLK} = 32$ MHz $f_{PCLK} = 64$ MHz
Sleep mode current Peripherals clock disabled ⁵⁾	I_{DDPSD} CC	–	1.2	–	mA	$f_{MCLK} = 1$ MHz $f_{PCLK} = 1$ MHz
Deep Sleep mode current ⁶⁾	I_{DDPDS} CC	–	0.24	–	mA	
Wake-up time from Sleep to Active mode ⁷⁾	t_{SSA} CC	–	6	–	cycles	
Wake-up time from Deep Sleep to Active mode ⁸⁾	t_{DSA} CC	–	280	–	μsec	

1) Not all parameters are 100% tested, but are verified by design/characterisation and test correlation.

2) The typical values are measured at $T_A = +25$ °C and $V_{DDP} = 5$ V.

3) CPU and all peripherals clock enabled, Flash is in active mode.

4) CPU is sleep, all peripherals clock enabled and Flash is in active mode.

5) CPU is sleep, Flash is powered down and code executed from RAM after wake-up.

6) CPU is sleep, peripherals clock disabled, Flash is powered down and code executed from RAM after wake-up.

7) CPU is sleep, Flash is in active mode during sleep mode.

8) CPU is sleep, Flash is in power down mode during deep sleep mode.

3.3 AC Parameters

3.3.1 Testing Waveforms

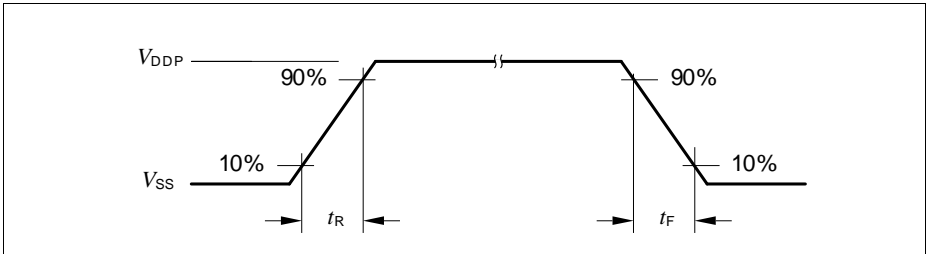


Figure 9 Rise/Fall Time Parameters

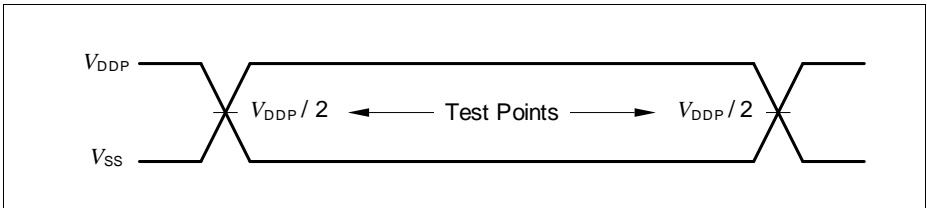


Figure 10 Testing Waveform, Output Delay

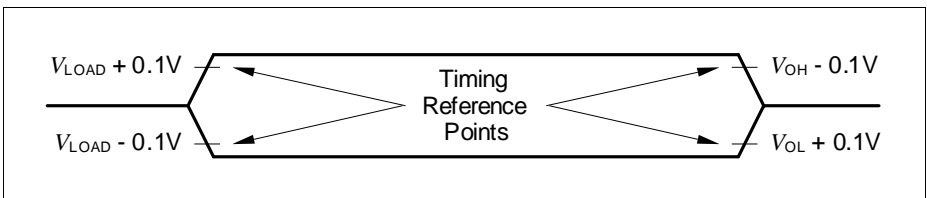


Figure 11 Testing Waveform, Output High Impedance

3.3.3 Power-Up and Supply Threshold Characteristics

Table 18 provides the characteristics of the supply threshold in XMC1100.

Table 18 Power-Up and Supply Threshold Parameters (Operating Conditions apply) ¹⁾

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
V_{DDP} ramp-up time	t_{RAMPUP} SR	$V_{DDP}/S_{VDDPrise}$	–	10^7	μs	
V_{DDP} slew rate	S_{VDDPOP} SR	0	–	0.1	$V/\mu s$	Slope during normal operation
	S_{VDDP10} SR	0	–	10	$V/\mu s$	Slope during fast transient within +/- 10% of V_{DDP}
	$S_{VDDPrise}$ SR	0	–	10	$V/\mu s$	Slope during power-on or restart after brownout event
	$S_{VDDPfall}$ ²⁾ SR	0	–	0.25	$V/\mu s$	Slope during supply falling out of the +/- 10% limits ³⁾
V_{DDP} prewarning voltage	V_{DDPPW} CC	2.1	2.25	2.4	V	ANAVDEL.VDEL_SELECT = 00 _B
		2.85	3	3.15	V	ANAVDEL.VDEL_SELECT = 01 _B
		4.2	4.4	4.6	V	ANAVDEL.VDEL_SELECT = 10 _B
V_{DDP} brownout reset voltage	V_{DDPBO} CC	1.55	1.62	1.75	V	calibrated, before user code starts running
Start-up time from power-on reset	t_{SSW} SR	–	320	–	μs	Time to the first user code instruction ⁴⁾

1) Not all parameters are 100% tested, but are verified by design/characterisation.

2) A capacitor of at least 100 nF has to be added between V_{DDP} and V_{SSP} to fulfill the requirement as stated for this parameter.

3.3.4 On-Chip Oscillator Characteristics

Table 19 provides the characteristics of the 64 MHz clock output from the digital controlled oscillator, DCO1 in XMC1100.

Table 19 64 MHz DCO1 Characteristics (Operating Conditions apply)

Parameter	Symbol		Limit Values			Unit	Test Conditions
			Min.	Typ.	Max.		
Nominal frequency	f_{NOM}	CC	63.5	64	64.5	MHz	under nominal conditions ¹⁾ after trimming
Accuracy	Δf_{LT}	CC	-1.7	–	3.4	%	with respect to $f_{\text{NOM}}(\text{typ})$, over temperature (0 °C to 85 °C) ²⁾
			-3.9	–	4.0	%	with respect to $f_{\text{NOM}}(\text{typ})$, over temperature (-40 °C to 105 °C) ²⁾
Accuracy with calibration based on temperature sensor	Δf_{LTT}	CC	-1.3	–	1.25	%	with respect to $f_{\text{NOM}}(\text{typ})$, over temperature ($T_A = 0$ °C to 105 °C) ²⁾
			-2.6	–	1.25	%	with respect to $f_{\text{NOM}}(\text{typ})$, over temperature ($T_A = -40$ °C to 105 °C) ²⁾

1) The deviation is relative to the factory trimmed frequency at nominal V_{DDC} and $T_A = +25$ °C.

2) Not subject to production test, verified by design/characterisation.

3.3.6 SPD Timing Requirements

The optimum SPD decision time between 0_B and 1_B is $0.75 \mu\text{s}$. With this value the system has maximum robustness against frequency deviations of the sampling clock on tool and on device side. However it is not always possible to exactly match this value with the given constraints for the sample clock. For instance for a oversampling rate of 4, the sample clock will be 8 MHz and in this case the closest possible effective decision time is 5.5 clock cycles ($0.69 \mu\text{s}$).

Table 22 Optimum Number of Sample Clocks for SPD

Sample Freq.	Sampling Factor	Sample Clocks 0_B	Sample Clocks 1_B	Effective Decision Time ¹⁾	Remark
8 MHz	4	1 to 5	6 to 12	$0.69 \mu\text{s}$	The other closest option ($0.81 \mu\text{s}$) for the effective decision time is less robust.

1) Nominal sample frequency period multiplied with $0.5 + (\text{max. number of } 0_B \text{ sample clocks})$

For a balanced distribution of the timing robustness of SPD between tool and device, the timing requirements for the tool are:

- Frequency deviation of the sample clock is +/- 5%
- Effective decision time is between $0.69 \mu\text{s}$ and $0.75 \mu\text{s}$ (calculated with nominal sample frequency)

3.3.7 Peripheral Timings

Note: These parameters are not subject to production test, but verified by design and/or characterization.

3.3.7.1 Synchronous Serial Interface (USIC SSC) Timing

The following parameters are applicable for a USIC channel operated in SSC mode.

Note: Operating Conditions apply.

Table 23 USIC SSC Master Mode Timing

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Slave select output SELO active to first SCLKOUT transmit edge	t_1 CC	80	–	–	ns	
Slave select output SELO inactive after last SCLKOUT receive edge	t_2 CC	0	–	–	ns	
Data output DOUT[3:0] valid time	t_3 CC	-10	–	10	ns	
Receive data input DX0/DX[5:3] setup time to SCLKOUT receive edge	t_4 SR	80	–	–	ns	
Data input DX0/DX[5:3] hold time from SCLKOUT receive edge	t_5 SR	0	–	–	ns	

Table 24 USIC SSC Slave Mode Timing

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Select input DX2 setup to first clock input DX1 transmit edge ¹⁾	t_{10} SR	10	–	–	ns	
Select input DX2 hold after last clock input DX1 receive edge ¹⁾	t_{11} SR	10	–	–	ns	

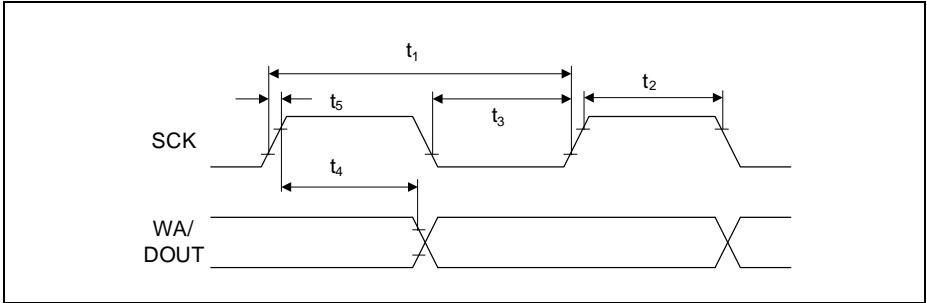


Figure 17 USIC IIS Master Transmitter Timing

Table 28 USIC IIS Slave Receiver Timing

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clock period	t_6 SR	$4/f_{MCLK}$	-	-	ns	
Clock HIGH	t_7 SR	$0.35 \times t_{6min}$	-	-	ns	
Clock Low	t_8 SR	$0.35 \times t_{6min}$	-	-	ns	
Set-up time	t_9 SR	$0.2 \times t_{6min}$	-	-	ns	
Hold time	t_{10} SR	10	-	-	ns	

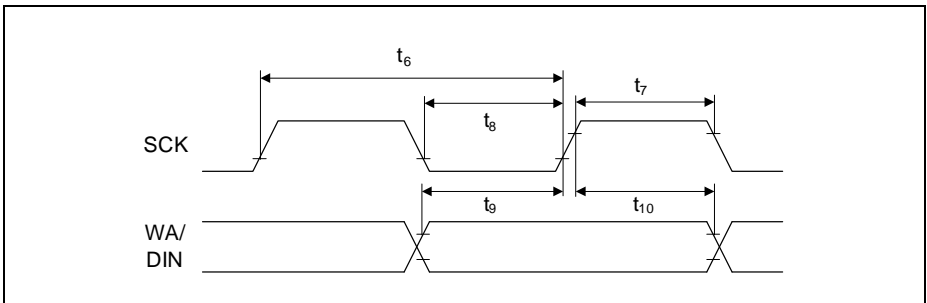


Figure 18 USIC IIS Slave Receiver Timing

5 Quality Declaration

Table 30 shows the characteristics of the quality parameters in the XMC1100.

Table 30 Quality Parameters

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
ESD susceptibility according to Human Body Model (HBM)	V_{HBM} SR	-	2000	V	Conforming to EIA/JESD22-A114-B
ESD susceptibility according to Charged Device Model (CDM) pins	V_{CDM} SR	-	500	V	Conforming to JESD22-C101-C
Moisture sensitivity level	MSL CC	-	3	-	JEDEC J-STD-020C